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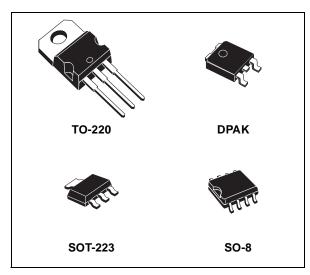
# LD1117 SERIES

# LOW DROP FIXED AND ADJUSTABLE POSITIVE VOLTAGE REGULATORS

- LOW DROPOUT VOLTAGE (1V TYP.)
- 2.85V DEVICE PERFORMANCES ARE SUITABLE FOR SCSI-2 ACTIVE TERMINATION
- OUTPUT CURRENT UP TO 800 mA
- FIXED OUTPUT VOLTAGE OF: 1.2V, 1.8V, 2.5V, 2.85V, 3.0V, 3.3V, 5.0V
- ADJUSTABLE VERSION AVAILABILITY (V<sub>rel</sub>=1.25V)
- INTERNAL CURRENT AND THERMAL LIMIT
- AVAILABLE IN ± 1% (AT 25°C) AND 2% IN FULL TEMPERATURE RANGE
- SUPPLY VOLTAGE REJECTION: 75dB (TYP.)

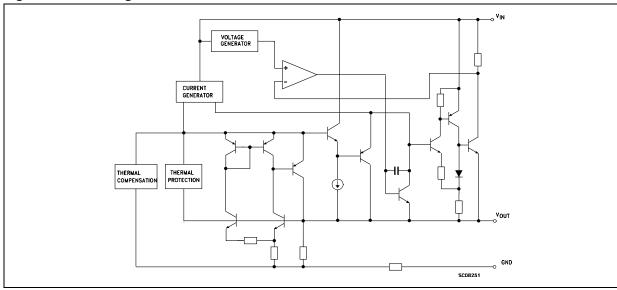
#### **DESCRIPTION**

The LD1117 is a LOW DROP Voltage Regulator able to provide up to 800mA of Output Current, available even in adjustable version (Vref=1.25V). Concerning fixed versions, are offered the following Output Voltages: 1.2V,1.8V,2.5V,2.85V, 3.0V 3.3V and 5.0V. The 2.85V type is ideal for SCSI-2 lines active termination. The device is supplied in: SOT-223, DPAK, SO-8 and TO-220. The SOT-223 and DPAK surface mount packages optimize the thermal characteristics even offering a relevant space saving effect. High efficiency is assured by NPN pass transistor. In fact in this



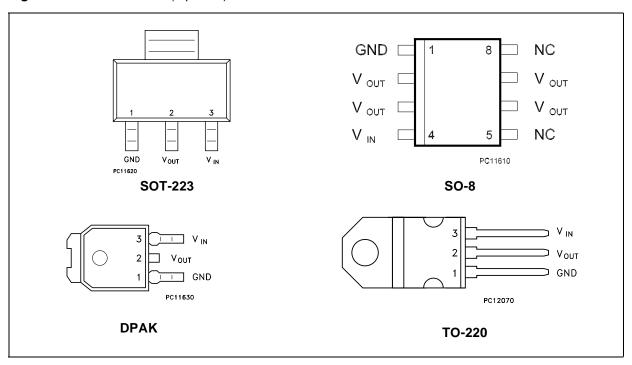
case, unlike than PNP one, the Quiescent Current flows mostly into the load. Only a very common  $10\mu F$  minimum capacitor is needed for stability. On chip trimming allows the regulator to reach a very tight output voltage tolerance, within  $\pm$  1% at 25°C. The ADJUSTABLE LD1117 is pin to pin compatible with the other standard. Adjustable voltage regulators maintaining the better performances in terms of Drop and Tolerance.

Figure 1: Block Diagram



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Figure 2: Pin Connection (top view)



NOTE: The TAB is connected to the  $V_{\mbox{\scriptsize OUT}}$ .

**Table 1: Order Codes** 

SOT-223	SO-8	DPAK	DPAK (T&R)	TO-220	OUTPUT VOLTAGE
LD1117S12TR	LD1117D12TR (*)	LD1117DT12 (*)	LD1117DT12TR	LD1117V12 (*)	1.2 V
LD1117S12CTR (*)	LD1117D12CTR (*)	LD1117DT12C (*)		LD1117V12C (*)	1.2 V
LD1117S18TR	LD1117D18TR (*)	LD1117DT18	LD1117DT18TR	LD1117V18	1.8 V
LD1117S18CTR (*)	LD1117D18CTR (*)	LD1117DT18C	LD1117DT18CTR	LD1117V18C (*)	1.8 V
LD1117S25TR	LD1117D25TR (*)	LD1117DT25	LD1117DT25TR	LD1117V25	2.5 V
LD1117S25CTR	LD1117D25CTR (*)	LD1117DT25C	LD1117DT25CTR	LD1117V25C	2.5 V
LD1117S28TR	LD1117D28TR (*)		LD1117DT28TR		2.85 V
LD1117S30TR	LD1117D30TR (*)				3 V
LD1117S33TR	LD1117D33TR	LD1117DT33	LD1117DT33TR	LD1117V33	3.3 V
LD1117S33CTR	LD1117D33CTR	LD1117DT33C	LD1117DT33CTR	LD1117V33C	3.3 V
LD1117S50TR	LD1117D50TR	LD1117DT50	LD1117DT50TR	LD1117V50	5 V
LD1117S50CTR	LD1117D50CTR (*)	LD1117DT50C	LD1117DT50CTR		5 V
LD1117STR	LD1117DTR (*)	LD1117DT	LD1117DTTR	LD1117V	ADJ FROM 1.25 TO 15V
LD1117SC-R	LD1117DC-R (*)	LD1117DTC (*)	LD1117DTC-R	LD1117VC (*)	ADJ FROM 1.25 TO 15V

(\*) Available on request

**Table 2: Absolute Maximum Ratings** 

Symbol	Parameter	Parameter		
V <sub>IN</sub>	DC Input Voltage	15	V	
P <sub>tot</sub>	Power Dissipation	12	W	
T <sub>stg</sub>	Storage Temperature Range		-40 to +150	°C
T <sub>op</sub>	Operating Junction Temperature Range	for C Version	-40 to +150	°C
		for standard Version	0 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied. Over the above suggested Max Power Dissipation a Short Circuit could definitively damage the device.

**Table 3: Thermal Data** 

Symbol	Parameter	SOT-223	SO-8	DPAK	TO-220	Unit
R <sub>thj-case</sub>	Thermal Resistance Junction-case	15	20	8	3	°C/W
R <sub>thj-amb</sub>	Thermal Resistance Junction-ambient				50	°C/W

Figure 3: Application Circuit (FOR 1.2 V)

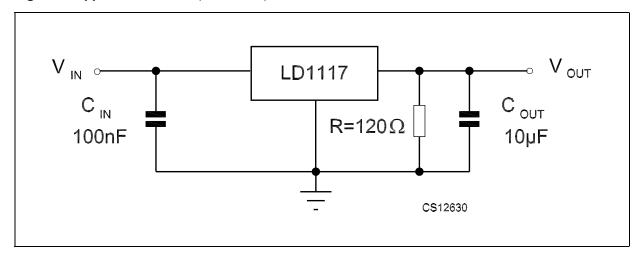
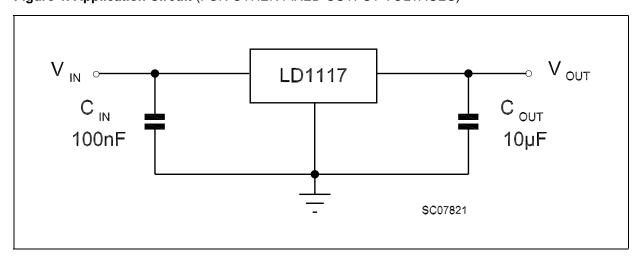


Figure 4: Application Circuit (FOR OTHER FIXED OUTPUT VOLTAGES)



**Table 4: Electrical Characteristics Of LD1117#12** (refer to the test circuits,  $T_J$  = 0 to 125°C,  $C_O$  = 10  $\mu$ F, R = 120  $\Omega$  between GND and OUT pins, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 3.2 \text{ V } I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	1.188	1.20	1.212	V
Vo	Reference Voltage	$I_O = 10 \text{ to } 800 \text{ mA}$ $V_{in} - V_O = 1.4 \text{ to } 10 \text{ V}$	1.140	1.20	1.260	V
$\Delta V_{O}$	Line Regulation	$V_{in} - V_{O} = 1.5 \text{ to } 13.75 \text{ V}$ $I_{O} = 10 \text{ mA}$		0.035	0.2	%
$\Delta V_{O}$	Load Regulation	$V_{in} - V_{O} = 3 \text{ V}$ $I_{O} = 10 \text{ to } 800 \text{ mA}$		0.1	0.4	%
$\Delta V_{O}$	Temperature Stability			0.5		%
$\Delta V_{O}$	Long Term Stability	1000 hrs, T <sub>J</sub> = 125°C		0.3		%
V <sub>in</sub>	Operating Input Voltage				15	V
I <sub>adj</sub>	Adjustment Pin Current	V <sub>in</sub> ≤ 15 V		60	120	μA
$\Delta I_{adj}$	Adjustment Pin Current Change	$V_{in} - V_{O} = 1.4 \text{ to } 10 \text{ V}$ $I_{O} = 10 \text{ to } 800 \text{ mA}$		1	5	μA
I <sub>O(min)</sub>	Minimum Load Current	V <sub>in</sub> = 15 V		2	5	mA
Io	Output Current	$V_{in} - V_O = 5 V$ $T_J = 25$ °C	800	950	1300	mA
eN	Output Noise (%V <sub>O</sub> )	B = 10Hz to 10KHz $T_J = 25$ °C		0.003		%
SVR	Supply Voltage Rejection	$I_{O} = 40 \text{ mA f} = 120 \text{Hz}$ $T_{J} = 25 ^{\circ}\text{C}$ $V_{in} - V_{O} = 3 \text{ V}$ $V_{ripple} = 1 \text{ V}_{PP}$	60	75		dB
V <sub>d</sub>	Dropout Voltage	I <sub>O</sub> = 100 mA		1	1.1	V
		I <sub>O</sub> = 500 mA		1.05	1.15	
		I <sub>O</sub> = 800 mA		1.10	1.2	
	Thermal Regulation	T <sub>a</sub> = 25°C 30ms Pulse		0.01	0.1	%/W

**Table 5: Electrical Characteristics Of LD1117#18** (refer to the test circuits,  $T_J$  = 0 to 125°C,  $C_O$  = 10  $\mu F$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 3.8 \text{ V } I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	1.78	1.8	1.82	V
Vo	Output Voltage	$I_{O} = 0 \text{ to } 800 \text{ mA}$ $V_{in} = 3.3 \text{ to } 8 \text{ V}$	1.76		1.84	V
$\Delta V_{O}$	Line Regulation	$V_{in} = 3.3 \text{ to } 8 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	6	mV
$\Delta V_{O}$	Load Regulation	$V_{in} = 3.3 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	10	mV
$\Delta V_{O}$	Temperature Stability			0.5		%
$\Delta V_{O}$	Long Term Stability	1000 hrs, T <sub>J</sub> = 125°C		0.3		%
V <sub>in</sub>	Operating Input Voltage	I <sub>O</sub> = 100 mA			10	V
I <sub>d</sub>	Quiescent Current	V <sub>in</sub> ≤ 8 V		5	10	mA
Io	Output Current	V <sub>in</sub> = 6.8 V T <sub>J</sub> = 25°C	800	950	1300	mA
eN	Output Noise Voltage	B =10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_{O} = 40 \text{ mA f} = 120 \text{Hz}$ $T_{J} = 25^{\circ}\text{C}$ $V_{in} = 5.5 \text{ V} \ V_{ripple} = 1 \ V_{PP}$	60	75		dB
V <sub>d</sub>	Dropout Voltage	I <sub>O</sub> = 100 mA		1	1.1	V
		I <sub>O</sub> = 500 mA		1.05	1.15	
		I <sub>O</sub> = 800 mA		1.10	1.2	
	Thermal Regulation	T <sub>a</sub> = 25°C 30ms Pulse		0.01	0.1	%/W

**Table 6: Electrical Characteristics Of LD1117#25** (refer to the test circuits,  $T_J = 0$  to 125°C,  $C_O = 10~\mu F$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 4.5 \text{ V } I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	2.475	2.5	2.525	V
Vo	Output Voltage	$I_{O} = 0 \text{ to } 800 \text{ mA}$ $V_{in} = 3.9 \text{ to } 10 \text{ V}$	2.45		2.55	V
$\Delta V_{O}$	Line Regulation	$V_{in} = 3.9 \text{ to } 10 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	6	mV
$\Delta V_{O}$	Load Regulation	$V_{in} = 3.9 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	10	mV
$\Delta V_{O}$	Temperature Stability			0.5		%
$\Delta V_{O}$	Long Term Stability	1000 hrs, T <sub>J</sub> = 125°C		0.3		%
V <sub>in</sub>	Operating Input Voltage	I <sub>O</sub> = 100 mA			15	V
I <sub>d</sub>	Quiescent Current	V <sub>in</sub> ≤ 10 V		5	10	mA
Io	Output Current	$V_{in} = 7.5 \text{ V } T_{J} = 25^{\circ}\text{C}$	800	950	1300	mA
eN	Output Noise Voltage	B =10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_{O}$ = 40 mA f = 120Hz $T_{J}$ = 25°C $V_{in}$ = 5.5 V $V_{ripple}$ = 1 $V_{PP}$	60	75		dB
V <sub>d</sub>	Dropout Voltage	I <sub>O</sub> = 100 mA		1	1.1	V
		I <sub>O</sub> = 500 mA		1.05	1.15	
		I <sub>O</sub> = 800 mA		1.10	1.2	
	Thermal Regulation	T <sub>a</sub> = 25°C 30ms Pulse		0.01	0.1	%/W

**Table 7: Electrical Characteristics Of LD1117#28** (refer to the test circuits,  $T_J$  = 0 to 125°C,  $C_O$  = 10  $\mu F$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 4.85 \text{ VI}_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	2.82	2.85	2.88	V
Vo	Output Voltage	$I_{O} = 0 \text{ to } 800 \text{ mA}$ $V_{in} = 4.25 \text{ to } 10 \text{ V}$	2.79		2.91	V
$\Delta V_{O}$	Line Regulation	V <sub>in</sub> = 4.25 to 10 V I <sub>O</sub> = 0 mA		1	6	mV
$\Delta V_{O}$	Load Regulation	$V_{in} = 4.25 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	10	mV
$\Delta V_{O}$	Temperature Stability			0.5		%
$\Delta V_{O}$	Long Term Stability	1000 hrs, T <sub>J</sub> = 125°C		0.3		%
V <sub>in</sub>	Operating Input Voltage	I <sub>O</sub> = 100 mA			15	V
I <sub>d</sub>	Quiescent Current	V <sub>in</sub> ≤ 10 V		5	10	mA
I <sub>O</sub>	Output Current	V <sub>in</sub> = 7.85 VT <sub>J</sub> = 25°C	800	950	1300	mA
eN	Output Noise Voltage	B = 10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_{O} = 40 \text{ mA f} = 120 \text{Hz}$ $T_{J} = 25^{\circ}\text{C}$ $V_{in} = 5.85 \text{ VV}_{ripple} = 1 \text{ V}_{PP}$	60	75		dB
V <sub>d</sub>	Dropout Voltage	I <sub>O</sub> = 100 mA		1	1.1	V
		I <sub>O</sub> = 500 mA		1.05	1.15	
		I <sub>O</sub> = 800 mA		1.10	1.2	
	Thermal Regulation	T <sub>a</sub> = 25°C 30ms Pulse		0.01	0.1	%/W

**Table 8: Electrical Characteristics Of LD1117#30** (refer to the test circuits,  $T_J = 0$  to 125°C,  $C_O = 10~\mu F$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 5 \text{ V}$ $I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	2.97	3	3.03	V
Vo	Output Voltage	$I_{O} = 0$ to 800 mA $V_{in} = 4.5$ to 10 V	2.94		3.06	V
$\Delta V_{O}$	Line Regulation	$V_{in} = 4.5 \text{ to } 12 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	6	mV
$\Delta V_{O}$	Load Regulation	$V_{in} = 4.5 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	10	mV
$\Delta V_{O}$	Temperature Stability			0.5		%
$\Delta V_{O}$	Long Term Stability	1000 hrs, T <sub>J</sub> = 125°C		0.3		%
V <sub>in</sub>	Operating Input Voltage	I <sub>O</sub> = 100 mA			15	V
I <sub>d</sub>	Quiescent Current	V <sub>in</sub> ≤ 12 V		5	10	mA
Io	Output Current	V <sub>in</sub> = 8 V T <sub>J</sub> = 25°C	800	950	1300	mA
eN	Output Noise Voltage	B =10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_O$ = 40 mA f = 120Hz $T_J$ = 25°C $V_{in}$ = 6 V $V_{ripple}$ = 1 $V_{PP}$	60	75		dB
V <sub>d</sub>	Dropout Voltage	I <sub>O</sub> = 100 mA		1	1.1	V
		I <sub>O</sub> = 500 mA		1.05	1.15	
		I <sub>O</sub> = 800 mA		1.10	1.2	
	Thermal Regulation	T <sub>a</sub> = 25°C 30ms Pulse		0.01	0.1	%/W

**Table 9: Electrical Characteristics Of LD1117#33** (refer to the test circuits,  $T_J$  = 0 to 125°C,  $C_O$  = 10  $\mu F$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 5.3 \text{ V } I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	3.267	3.3	3.333	V
Vo	Output Voltage	$I_{O} = 0$ to 800 mA $V_{in} = 4.75$ to 10 V	3.235		3.365	V
$\Delta V_{O}$	Line Regulation	$V_{in} = 4.75 \text{ to } 15 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	6	mV
$\Delta V_{O}$	Load Regulation	V <sub>in</sub> = 4.75 V I <sub>O</sub> = 0 to 800 mA		1	10	mV
$\Delta V_{O}$	Temperature Stability			0.5		%
$\Delta V_{O}$	Long Term Stability	1000 hrs, T <sub>J</sub> = 125°C		0.3		%
V <sub>in</sub>	Operating Input Voltage	I <sub>O</sub> = 100 mA			15	V
I <sub>d</sub>	Quiescent Current	V <sub>in</sub> ≤ 15 V		5	10	mA
Io	Output Current	V <sub>in</sub> = 8.3 V T <sub>J</sub> = 25°C	800	950	1300	mA
eN	Output Noise Voltage	B = 10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_{O} = 40 \text{ mA f} = 120 \text{Hz}$ $T_{J} = 25^{\circ}\text{C}$ $V_{in} = 6.3 \text{ V } V_{ripple} = 1 \text{ V}_{PP}$	60	75		dB
V <sub>d</sub>	Dropout Voltage	I <sub>O</sub> = 100 mA		1	1.1	V
		I <sub>O</sub> = 500 mA		1.05	1.15	
		I <sub>O</sub> = 800 mA		1.10	1.2	
	Thermal Regulation	T <sub>a</sub> = 25°C 30ms Pulse		0.01	0.1	%/W

**Table 10: Electrical Characteristics Of LD1117#50** (refer to the test circuits,  $T_J$  = 0 to 125°C,  $C_O$  = 10  $\mu F$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 7 \text{ V}$ $I_O = 10 \text{ mA}$ $T_J = 25^{\circ}\text{C}$	4.95	5	5.05	V
Vo	Output Voltage	$I_{O} = 0$ to 800 mA $V_{in} = 6.5$ to 15 V	4.9		5.1	V
$\Delta V_{O}$	Line Regulation	$V_{in} = 6.5 \text{ to } 15 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	10	mV
$\Delta V_{O}$	Load Regulation	$V_{in} = 6.5 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	15	mV
$\Delta V_{O}$	Temperature Stability			0.5		%
$\Delta V_{O}$	Long Term Stability	1000 hrs, T <sub>J</sub> = 125°C		0.3		%
V <sub>in</sub>	Operating Input Voltage	I <sub>O</sub> = 100 mA			15	V
I <sub>d</sub>	Quiescent Current	V <sub>in</sub> ≤ 15 V		5	10	mA
I <sub>O</sub>	Output Current	V <sub>in</sub> = 10 V T <sub>J</sub> = 25°C	800	950	1300	mA
eN	Output Noise Voltage	B =10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_O = 40 \text{ mA f} = 120 \text{Hz}$ $T_J = 25^{\circ}\text{C}$ $V_{in} = 8 \text{ V}$ $V_{ripple} = 1 \text{ V}_{PP}$	60	75		dB
V <sub>d</sub>	Dropout Voltage	I <sub>O</sub> = 100 mA		1	1.1	V
		I <sub>O</sub> = 500 mA		1.05	1.15	
		I <sub>O</sub> = 800 mA		1.10	1.2	
	Thermal Regulation	T <sub>a</sub> = 25°C 30ms Pulse		0.01	0.1	%/W

Table 11: Electrical Characteristics Of LD1117 (ADJUSTABLE) (refer to the test circuits,  $T_J=0$  to 125°C,  $C_O=10~\mu F$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>ref</sub>	Reference Voltage	$V_{in} - V_O = 2 V$ $I_O = 10 \text{ mA}$ $T_J = 25^{\circ}\text{C}$	1.238	1.25	1.262	V
V <sub>ref</sub>	Reference Voltage	$I_O = 10 \text{ to } 800 \text{ mA}$ $V_{in} - V_O = 1.4 \text{ to } 10$ $V$	1.225		1.275	V
$\Delta V_{O}$	Line Regulation	$V_{in} - V_{O} = 1.5 \text{ to } 13.75 \text{ V}$ $I_{O} = 10 \text{ mA}$		0.035	0.2	%
$\Delta V_{O}$	Load Regulation	$V_{in} - V_{O} = 3 \text{ V}$ $I_{O} = 10 \text{ to } 800 \text{ mA}$		0.1	0.4	%
$\Delta V_{O}$	Temperature Stability			0.5		%
$\Delta V_{O}$	Long Term Stability	1000 hrs, T <sub>J</sub> = 125°C		0.3		%
V <sub>in</sub>	Operating Input Voltage				15	V
I <sub>adj</sub>	Adjustment Pin Current	V <sub>in</sub> ≤ 15 V		60	120	μA
$\Delta I_{adj}$	Adjustment Pin Current Change	$V_{in} - V_{O} = 1.4 \text{ to } 10 \text{ V}$ $I_{O} = 10 \text{ to } 800 \text{ mA}$		1	5	μA
I <sub>O(min)</sub>	Minimum Load Current	V <sub>in</sub> = 15 V		2	5	mA
Io	Output Current	$V_{in} - V_O = 5 V$ $T_J = 25$ °C	800	950	1300	mA
eN	Output Noise (%V <sub>O</sub> )	B = 10Hz to 10KHz $T_J = 25$ °C		0.003		%
SVR	Supply Voltage Rejection	$I_O = 40$ mA f = 120Hz $T_J = 25$ °C $V_{in}$ - $V_O = 3$ V $V_{ripple} = 1$ $V_{PP}$	60	75		dB
V <sub>d</sub>	Dropout Voltage	I <sub>O</sub> = 100 mA		1	1.1	V
		I <sub>O</sub> = 500 mA		1.05	1.15	
		I <sub>O</sub> = 800 mA		1.10	1.2	
	Thermal Regulation	T <sub>a</sub> = 25°C 30ms Pulse		0.01	0.1	%/W

**Table 12: Electrical Characteristics Of LD1117#12C** (refer to the test circuits,  $T_J$  = 0 to 125°C,  $C_O$  = 10  $\mu$ F, R = 120  $\Omega$  between GND and OUT pins, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>ref</sub>	Reference Voltage	$V_{in} - V_{O} = 2V I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	1.176	1.20	1.224	V
V <sub>ref</sub>	Reference Voltage	$I_O = 10 \text{ to } 800 \text{ mA}$ $V_{in} - V_O = 1.4 \text{ to } 10$	1.120	1.20	1.280	V
$\Delta V_{O}$	Line Regulation	$V_{in} - V_{O} = 1.5 \text{ to } 13.75 \text{ V}$ $I_{O} = 10 \text{ mA}$			1	%
$\Delta V_{O}$	Load Regulation	$V_{in} - V_{O} = 3 \text{ V}$ $I_{O} = 10 \text{ to } 800 \text{ mA}$			1	%
$\Delta V_{O}$	Temperature Stability			0.5		%
$\Delta V_{O}$	Long Term Stability	1000 hrs, T <sub>J</sub> = 125°C		0.3		%
V <sub>in</sub>	Operating Input Voltage				15	V
I <sub>adj</sub>	Adjustment Pin Current	V <sub>in</sub> ≤ 15 V		60	120	μA
$\Delta I_{adj}$	Adjustment Pin Current Change	$V_{in} - V_{O} = 1.4 \text{ to } 10 \text{ V}$ $I_{O} = 10 \text{ to } 800 \text{ mA}$		1	5	μA
I <sub>O(min)</sub>	Minimum Load Current	V <sub>in</sub> = 15 V		2	5	mA
I <sub>O</sub>	Output Current	$V_{in} - V_O = 5 V$ $T_J = 25$ °C	800	950	1300	mA
eN	Output Noise (%V <sub>O</sub> )	B = 10Hz to 10KHz $T_J = 25$ °C		0.003		%
SVR	Supply Voltage Rejection	$I_O$ = 40 mA f = 120Hz $T_J$ = 25°C $V_{in}$ - $V_O$ = 3 V $V_{ripple}$ = 1 $V_{PP}$	60	75		dB
$V_d$	Dropout Voltage	$I_{O} = 100 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1	1.1	V
		$I_{O} = 500 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.05	1.2	
		$I_{O} = 800 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.10	1.3	
	Thermal Regulation	T <sub>a</sub> = 25°C 30ms Pulse		0.01	0.1	%/W

**Table 13: Electrical Characteristics Of LD1117#18C** (refer to the test circuits,  $T_J$  = -40 to 125°C,  $C_O$  = 10  $\mu F$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 3.8 \text{ V } I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	1.76	1.8	1.84	V
Vo	Output Voltage	$I_{O} = 0 \text{ to } 800 \text{ mA}$ $V_{in} = 3.9 \text{ to } 10 \text{ V}$	1.73		1.87	V
$\Delta V_{O}$	Line Regulation	V <sub>in</sub> = 3.3 to 8 V I <sub>O</sub> = 0 mA		1	30	mV
$\Delta V_{O}$	Load Regulation	$V_{in} = 3.3 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	30	mV
$\Delta V_{O}$	Temperature Stability			0.5		%
$\Delta V_{O}$	Long Term Stability	1000 hrs, T <sub>J</sub> = 125°C		0.3		%
V <sub>in</sub>	Operating Input Voltage	I <sub>O</sub> = 100 mA			10	V
I <sub>d</sub>	Quiescent Current	$V_{in} \le 8 V$		5	10	mA
Io	Output Current	$V_{in} = 6.8 \text{ V } T_{J} = 25^{\circ}\text{C}$	800	950	1300	mA
eN	Output Noise Voltage	B = 10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_O = 40$ mA f = 120Hz $T_J = 25$ °C $V_{in} = 5.5$ V $V_{ripple} = 1$ V <sub>PP</sub>	60	75		dB
V <sub>d</sub>	Dropout Voltage	$I_{O} = 100 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1	1.1	V
		$I_{O} = 500 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.05	1.15	
		$I_{O} = 800 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.10	1.2	
V <sub>d</sub>	Dropout Voltage	I <sub>O</sub> = 100 mA			1.1	V
		I <sub>O</sub> = 500 mA			1.2	
		I <sub>O</sub> = 800 mA			1.3	
	Thermal Regulation	T <sub>a</sub> = 25°C 30ms Pulse		0.01	0.1	%/W

**Table 14: Electrical Characteristics Of LD1117#25C** (refer to the test circuits,  $T_J$  = -40 to 125°C,  $C_O$  = 10  $\mu F$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 4.5 \text{ V } I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	2.45	2.5	2.55	V
Vo	Output Voltage	$I_{O} = 0$ to 800 mA $V_{in} = 3.9$ to 10 V	2.4		2.6	V
$\Delta V_{O}$	Line Regulation	$V_{in} = 3.9 \text{ to } 10 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	30	mV
$\Delta V_{O}$	Load Regulation	$V_{in} = 3.9 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	30	mV
$\Delta V_{O}$	Temperature Stability			0.5		%
$\Delta V_{O}$	Long Term Stability	1000 hrs, T <sub>J</sub> = 125°C		0.3		%
V <sub>in</sub>	Operating Input Voltage	I <sub>O</sub> = 100 mA			15	V
I <sub>d</sub>	Quiescent Current	$V_{in} \le 10 \text{ V}$		5	10	mA
Io	Output Current	$V_{in} = 7.5 \text{ V } T_{J} = 25^{\circ}\text{C}$	800	950	1300	mA
eN	Output Noise Voltage	B = 10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_{O} = 40 \text{ mA f} = 120 \text{Hz}$ $T_{J} = 25^{\circ}\text{C}$ $V_{in} = 5.5 \text{ V}$ $V_{ripple} = 1 \text{ V}_{PP}$	60	75		dB
V <sub>d</sub>	Dropout Voltage	$I_{O} = 100 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1	1.1	V
		$I_{O} = 500 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.05	1.15	
		$I_{O} = 800 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.10	1.2	
$V_d$	Dropout Voltage	I <sub>O</sub> = 100 mA			1.1	V
		I <sub>O</sub> = 500 mA			1.2	
		I <sub>O</sub> = 800 mA			1.3	
	Thermal Regulation	T <sub>a</sub> = 25°C 30ms Pulse		0.01	0.1	%/W

**Table 15: Electrical Characteristics Of LD1117#30C** (refer to the test circuits,  $T_J$  = -40 to 125°C,  $C_O$  = 10  $\mu F$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 5 \text{ V}$ $I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	2.94	3	3.06	V
Vo	Output Voltage	$I_{O} = 0$ to 800 mA $V_{in} = 4.5$ to 10 V	2.88		3.12	V
$\Delta V_{O}$	Line Regulation	$V_{in} = 4.5 \text{ to } 12 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	30	mV
$\Delta V_{O}$	Load Regulation	$V_{in} = 4.5 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	30	mV
$\Delta V_{O}$	Temperature Stability			0.5		%
$\Delta V_{O}$	Long Term Stability	1000 hrs, T <sub>J</sub> = 125°C		0.3		%
V <sub>in</sub>	Operating Input Voltage	I <sub>O</sub> = 100 mA			15	V
I <sub>d</sub>	Quiescent Current	V <sub>in</sub> ≤ 12 V		5	10	mA
Io	Output Current	$V_{in} = 8 \text{ V}$ $T_J = 25^{\circ}\text{C}$	800	950	1300	mA
eN	Output Noise Voltage	B =10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_O$ = 40 mA f = 120Hz $T_J$ = 25°C $V_{in}$ = 6 V $V_{ripple}$ = 1 $V_{PP}$	60	75		dB
V <sub>d</sub>	Dropout Voltage	$I_{O} = 100 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1	1.1	V
		$I_{O} = 500 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.05	1.15	
		$I_{O} = 800 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.10	1.2	
V <sub>d</sub>	Dropout Voltage	I <sub>O</sub> = 100 mA			1.1	V
		I <sub>O</sub> = 500 mA			1.2	
		I <sub>O</sub> = 800 mA			1.3	
	Thermal Regulation	T <sub>a</sub> = 25°C 30ms Pulse		0.01	0.1	%/W

**Table 16: Electrical Characteristics Of LD1117#33C** (refer to the test circuits,  $T_J$  = -40 to 125°C,  $C_O$  = 10  $\mu F$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 5.3 \text{ V } I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	3.24	3.3	3.36	V
Vo	Output Voltage	$I_{O} = 0$ to 800 mA $V_{in} = 4.75$ to 10 V	3.16		3.44	V
$\Delta V_{O}$	Line Regulation	$V_{in} = 4.75 \text{ to } 15 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	30	mV
$\Delta V_{O}$	Load Regulation	$V_{in} = 4.75 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	30	mV
$\Delta V_{O}$	Temperature Stability			0.5		%
$\Delta V_{O}$	Long Term Stability	1000 hrs, T <sub>J</sub> = 125°C		0.3		%
V <sub>in</sub>	Operating Input Voltage	I <sub>O</sub> = 100 mA			15	V
I <sub>d</sub>	Quiescent Current	V <sub>in</sub> ≤ 15 V		5	10	mA
Io	Output Current	$V_{in} = 8.3 \text{ V } T_{J} = 25^{\circ}\text{C}$	800	950	1300	mA
eN	Output Noise Voltage	B = 10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_O$ = 40 mA f = 120Hz $T_J$ = 25°C $V_{in}$ = 6.3 V $V_{ripple}$ = 1 $V_{PP}$	60	75		dB
$V_d$	Dropout Voltage	$I_{O} = 100 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1	1.1	V
		$I_{O} = 500 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.05	1.15	
		$I_{O} = 800 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.10	1.2	
$V_d$	Dropout Voltage	I <sub>O</sub> = 100 mA			1.1	V
		I <sub>O</sub> = 500 mA			1.2	
		I <sub>O</sub> = 800 mA			1.3	
	Thermal Regulation	T <sub>a</sub> = 25°C 30ms Pulse		0.01	0.1	%/W

**Table 17: Electrical Characteristics Of LD1117#50C** (refer to the test circuits,  $T_J$  = -40 to 125°C,  $C_O$  = 10  $\mu F$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$V_{in} = 7 \text{ V}$ $I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	4.9	5	5.1	V
Vo	Output Voltage	$I_{O} = 0$ to 800 mA $V_{in} = 6.5$ to 15 V	4.8		5.2	V
$\Delta V_{O}$	Line Regulation	$V_{in} = 6.5 \text{ to } 15 \text{ V}$ $I_{O} = 0 \text{ mA}$		1	50	mV
$\Delta V_{O}$	Load Regulation	$V_{in} = 6.5 \text{ V}$ $I_{O} = 0 \text{ to } 800 \text{ mA}$		1	50	mV
$\Delta V_{O}$	Temperature Stability			0.5		%
$\Delta V_{O}$	Long Term Stability	1000 hrs, T <sub>J</sub> = 125°C		0.3		%
V <sub>in</sub>	Operating Input Voltage	I <sub>O</sub> = 100 mA			15	V
I <sub>d</sub>	Quiescent Current	$V_{in} \le 15 \text{ V}$		5	10	mA
I <sub>O</sub>	Output Current	V <sub>in</sub> = 10 V T <sub>J</sub> = 25°C	800	950	1300	mA
eN	Output Noise Voltage	B =10Hz to 10KHz $T_J = 25$ °C		100		μV
SVR	Supply Voltage Rejection	$I_O = 40 \text{ mA } f = 120 \text{Hz}$ $T_J = 25 ^{\circ}\text{C}$ $V_{in} = 8 \text{ V}$ $V_{ripple} = 1 \text{ V}_{PP}$	60	75		dB
V <sub>d</sub>	Dropout Voltage	$I_{O} = 100 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1	1.1	V
		$I_{O} = 500 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.05	1.15	
		$I_{O} = 800 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.10	1.2	
V <sub>d</sub>	Dropout Voltage	I <sub>O</sub> = 100 mA			1.1	V
		I <sub>O</sub> = 500 mA			1.2	
		I <sub>O</sub> = 800 mA			1.3	
	Thermal Regulation	T <sub>a</sub> = 25°C 30ms Pulse		0.01	0.1	%/W

Table 18: Electrical Characteristics Of LD1117C (ADJUSTABLE) (refer to the test circuits,  $T_J$  = -40 to 125°C,  $C_O$  = 10  $\mu F$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
$V_{ref}$	Reference Voltage	$V_{in} - V_{O} = 2 \text{ V}$ $I_{O} = 10 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$	1.225	1.25	1.275	V
V <sub>ref</sub>	Reference Voltage	$I_O = 10 \text{ to } 800 \text{ mA}$ $V_{in} - V_O = 1.4 \text{ to } 10$ $V$	1.2		1.3	V
$\Delta V_{O}$	Line Regulation	$V_{in} - V_{O} = 1.5 \text{ to } 13.75 \text{ V}$ $I_{O} = 10 \text{ mA}$			1	%
$\Delta V_{O}$	Load Regulation	$V_{in} - V_{O} = 3 \text{ V}$ $I_{O} = 10 \text{ to } 800 \text{ mA}$			1	%
$\Delta V_{O}$	Temperature Stability			0.5		%
$\Delta V_{O}$	Long Term Stability	1000 hrs, T <sub>J</sub> = 125°C		0.3		%
V <sub>in</sub>	Operating Input Voltage				15	V
I <sub>adj</sub>	Adjustment Pin Current	V <sub>in</sub> ≤ 15 V		60	120	μΑ
$\Delta I_{adj}$	Adjustment Pin Current Change	$V_{in} - V_{O} = 1.4 \text{ to } 10 \text{ V}$ $I_{O} = 10 \text{ to } 800 \text{ mA}$		1	10	μA
I <sub>O(min)</sub>	Minimum Load Current	V <sub>in</sub> = 15 V		2	5	mA
Io	Output Current	$V_{in} - V_O = 5 \text{ V}$ $T_J = 25^{\circ}\text{C}$	800	950	1300	mA
eN	Output Noise (%V <sub>O</sub> )	B =10Hz to 10KHz $T_J = 25$ °C		0.003		%
SVR	Supply Voltage Rejection	$I_O = 40$ mA f = 120Hz $T_J = 25$ °C $V_{in}$ - $V_O = 3$ V $V_{ripple} = 1$ $V_{PP}$	60	75		dB
V <sub>d</sub>	Dropout Voltage	$I_{O} = 100 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1	1.1	V
		$I_{O} = 500 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.05	1.15	
		$I_{O} = 800 \text{ mA}$ $T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.10	1.2	
V <sub>d</sub>	Dropout Voltage	I <sub>O</sub> = 100 mA			1.1	V
		I <sub>O</sub> = 500 mA			1.2	
		I <sub>O</sub> = 800 mA			1.3	
	Thermal Regulation	T <sub>a</sub> = 25°C 30ms Pulse		0.01	0.1	%/W

#### **TYPICAL APPLICATIONS**

Figure 5: Negative Supply

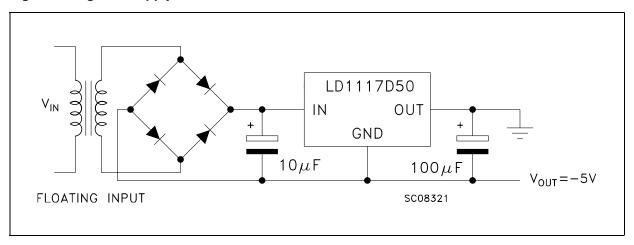


Figure 6: Active Terminator for SCSI-2 BUS

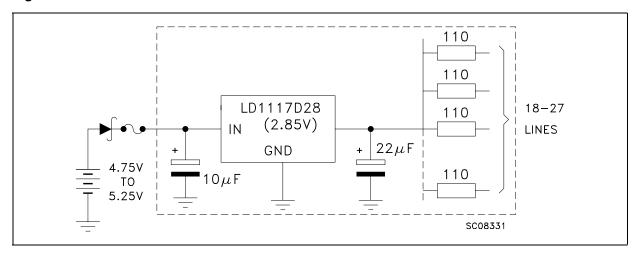


Figure 7: Circuit for Increasing Output Voltage

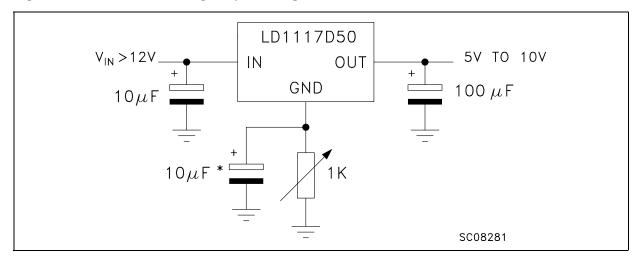
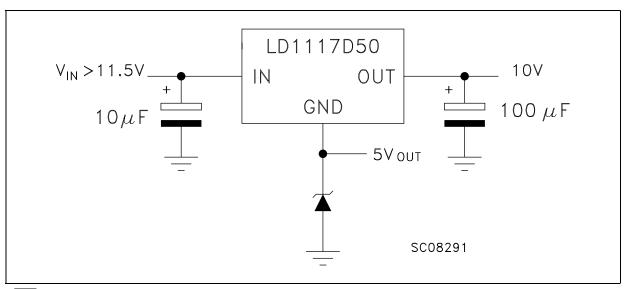
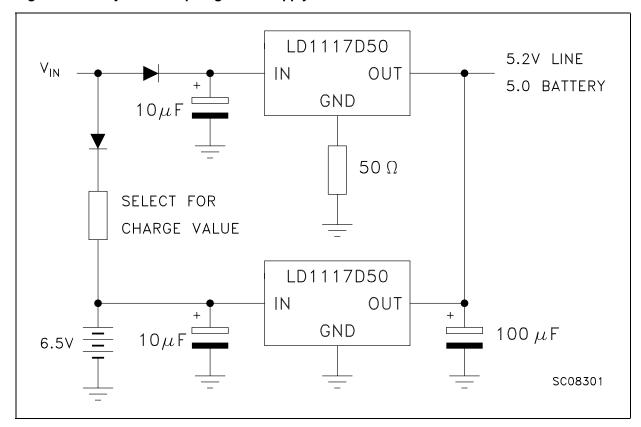


Figure 8: Voltage Regulator With Reference



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Figure 9: Battery Backed-up Regulated Supply



FEEDBACK PATH MUR410 3.3V OUTPUT (TYPICAL) ∎470μF LD1117D50 MUR410 +5V OUT IN 0.5A  $10 \mu F$ **GND** 1N4002  $470 \mu F$  $+V_{IN}$ LD1117D50 MUR410 **SWITCHING** IN OUT REGULATOR  $10\mu F$ GND 1N4002  $470 \mu F$ -5V0.5A SC08311

Figure 10: Post-Regulated Dual Supply

#### **LD1117 ADJUSTABLE: APPLICATION NOTE**

The LD1117 ADJUSTABLE has a thermal stabilized 1.25 $\pm$ 0.012V reference voltage between the OUT and ADJ pins. I<sub>ADJ</sub> is 60 $\mu$ A typ. (120 $\mu$ A max.) and  $\Delta$ I<sub>ADJ</sub> is 1 $\mu$ A typ. (5 $\mu$ A max.).

R1 is normally fixed to  $120\Omega$ . From figure 11 we obtain:

 $V_{OUT} = V_{REF} + R2 (I_{ADJ} + I_{R1}) = V_{REF} + R2 (I_{ADJ} + V_{REF}/R1) = V_{REF} (1 + R2/R1) + R2 x I_{ADJ}$ . In normal application R2 value is in the range of few kohm, so the R2 x  $I_{DJ}$  product could not be considered in the  $V_{OUT}$  calculation; then the above expression becomes:

$$V_{OLIT} = V_{RFF} (1 + R2 / R1).$$

In order to have the better load regulation it is important to realize a good Kelvin connection of R1 and R2 resistors. In particular R1 connection must be realized very close to OUT and ADJ pin, while R2 ground connection must be placed as near as possible to the negative Load pin. Ripple rejection can be improved by introducing a 10µF electrolytic capacitor placed in parallel to the R2 resistor (see Fig. 12).

Figure 11: Adjustable Output Voltage Application

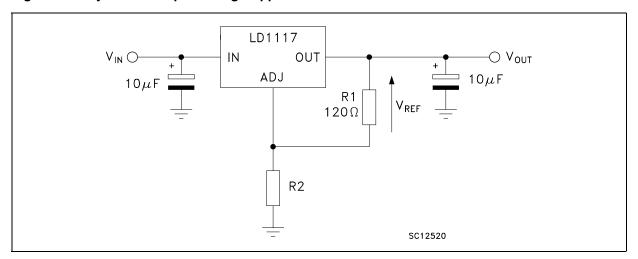
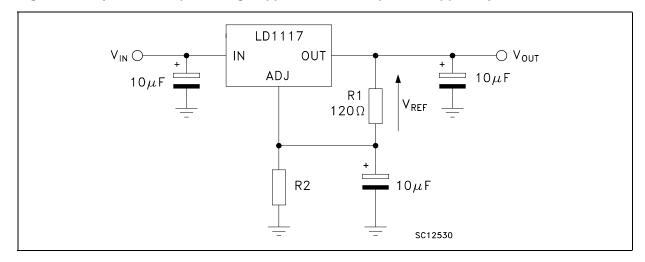


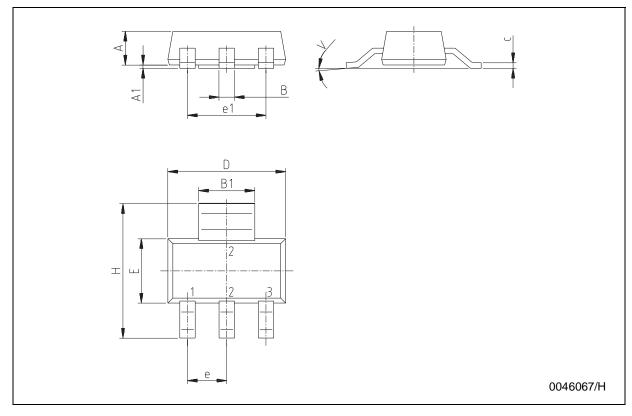
Figure 12: Adjustable Output Voltage Application with improved Ripple Rejection



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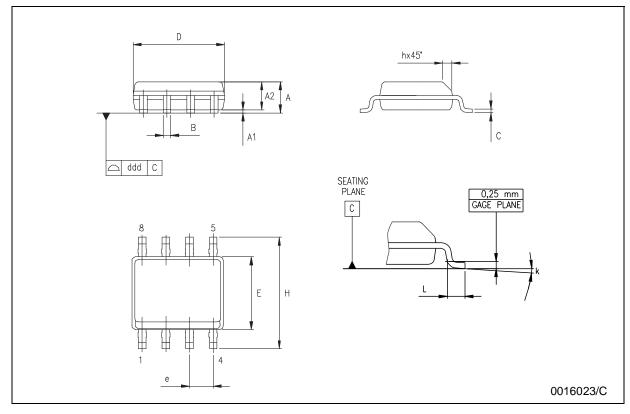
## **SOT-223 MECHANICAL DATA**

DIM		mm.		mils			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А			1.8			70.9	
A1	0.02		0.1	0.8		3.9	
В	0.6	0.7	0.85	23.6	27.6	33.5	
B1	2.9	3	3.15	114.2	118.1	124.0	
С	0.24	0.26	0.35	9.4	10.2	13.8	
D	6.3	6.5	6.7	248.0	255.9	263.8	
е		2.3			90.6		
e1		4.6			181.1		
E	3.3	3.5	3.7	129.9	137.8	145.7	
Н	6.7	7	7.3	129.9	137.8	145.7	
V			10°			10°	



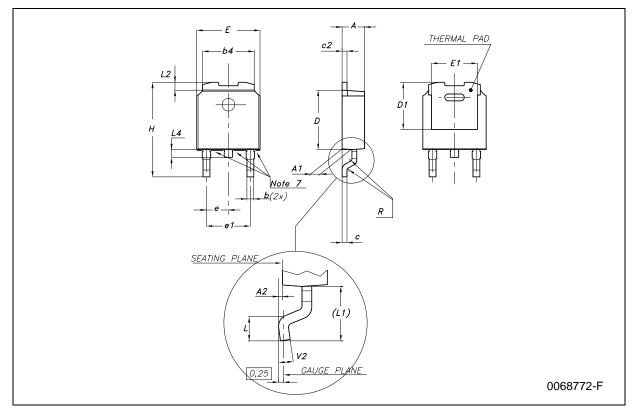
## **SO-8 MECHANICAL DATA**

DIM.		mm.		inch			
DIWI.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
Α	1.35		1.75	0.053		0.069	
A1	0.10		0.25	0.04		0.010	
A2	1.10		1.65	0.043		0.065	
В	0.33		0.51	0.013		0.020	
С	0.19		0.25	0.007		0.010	
D	4.80		5.00	0.189		0.197	
Е	3.80		4.00	0.150		0.157	
е		1.27			0.050		
Н	5.80		6.20	0.228		0.244	
h	0.25		0.50	0.010		0.020	
L	0.40		1.27	0.016		0.050	
k			8° (n	nax.)	•	•	
ddd			0.1			0.04	



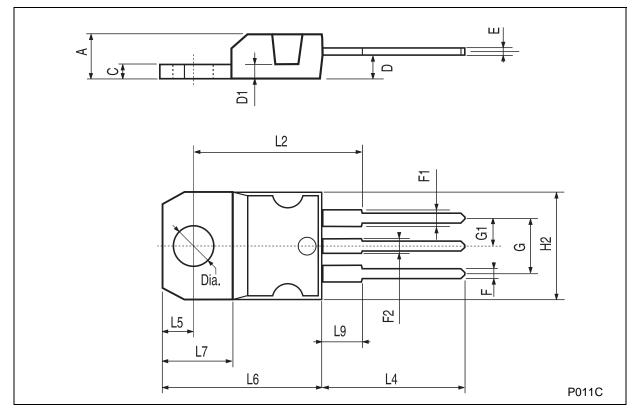
# **DPAK MECHANICAL DATA**

DIM		mm.		inch			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А	2.2		2.4	0.086		0.094	
A1	0.9		1.1	0.035		0.043	
A2	0.03		0.23	0.001		0.009	
В	0.64		0.9	0.025		0.035	
b4	5.2		5.4	0.204		0.212	
С	0.45		0.6	0.017		0.023	
C2	0.48		0.6	0.019		0.023	
D	6		6.2	0.236		0.244	
D1		5.1			0.200		
Е	6.4		6.6	0.252		0.260	
E1		4.7			0.185		
е		2.28			0.090		
e1	4.4		4.6	0.173		0.181	
Н	9.35		10.1	0.368		0.397	
L	1			0.039			
(L1)		2.8			0.110		
L2		0.8			0.031		
L4	0.6		1	0.023		0.039	

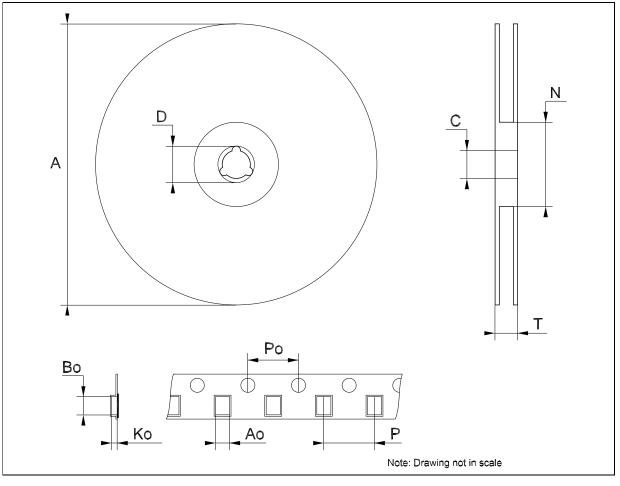


## **TO-220 MECHANICAL DATA**

DIM		mm.		inch		
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
Α	4.40		4.60	0.173		0.181
С	1.23		1.32	0.048		0.051
D	2.40		2.72	0.094		0.107
D1		1.27			0.050	
E	0.49		0.70	0.019		0.027
F	0.61		0.88	0.024		0.034
F1	1.14		1.70	0.044		0.067
F2	1.14		1.70	0.044		0.067
G	4.95		5.15	0.194		0.203
G1	2.4		2.7	0.094		0.106
H2	10.0		10.40	0.393		0.409
L2		16.4			0.645	
L4	13.0		14.0	0.511		0.551
L5	2.65		2.95	0.104		0.116
L6	15.25		15.75	0.600		0.620
L7	6.2		6.6	0.244		0.260
L9	3.5		3.93	0.137		0.154
DIA.	3.75		3.85	0.147		0.151

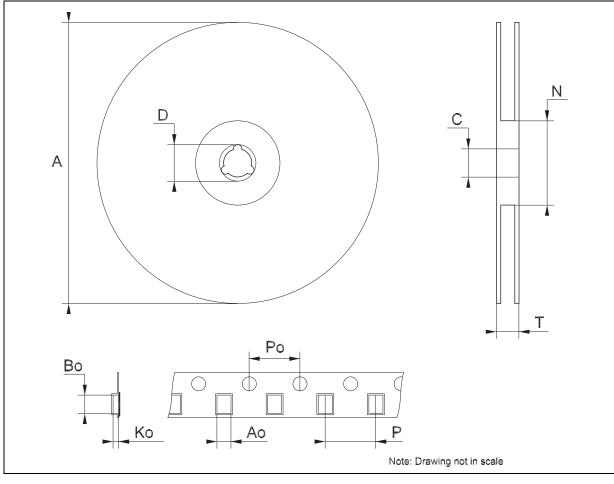


DIM		mm.		inch			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А			330			12.992	
С	12.8	13.0	13.2	0.504	0.512	0.519	
D	20.2			0.795			
N	60			2.362			
Т			14.4			0.567	
Ao	6.73	6.83	6.93	0.265	0.269	0.273	
Во	7.32	7.42	7.52	0.288	0.292	0.296	
Ko	1.78		2	0.070		0.078	
Po	3.9	4.0	4.1	0.153	0.157	0.161	
Р	7.9	8.0	8.1	0.311	0.315	0.319	

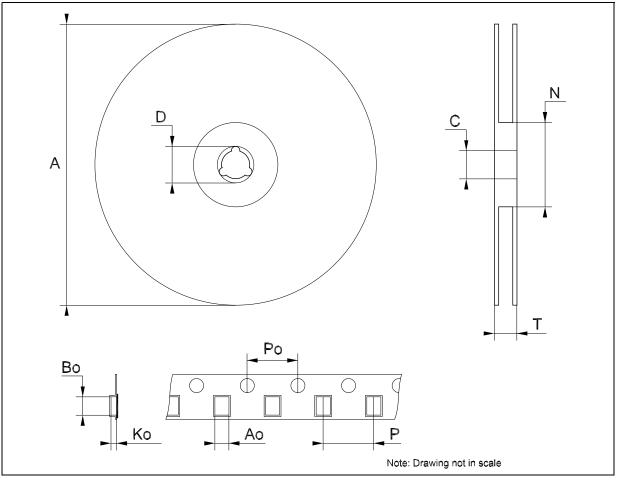


# Tape & Reel SO-8 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	8.1		8.5	0.319		0.335
Во	5.5		5.9	0.216		0.232
Ko	2.1		2.3	0.082		0.090
Ро	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319



DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А			330			12.992
С	12.8	13.0	13.2	0.504	0.512	0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	6.80	6.90	7.00	0.268	0.272	0.2.76
Во	10.40	10.50	10.60	0.409	0.413	0.417
Ko	2.55	2.65	2.75	0.100	0.104	0.105
Po	3.9	4.0	4.1	0.153	0.157	0.161
Р	7.9	8.0	8.1	0.311	0.315	0.319



#### **LD1117 SERIES**

**Table 19: Revision History** 

Date	Revision	Description of Changes
22-Sep-2004	15.0	Add new Part Number #12C; Typing Error: Note on table 2.
25-Oct-2004	16.0	Add V <sub>ref</sub> Reference Voltage on Table 12.
18-Jul-2005	17.0	The DPAK Mechanical Data has been updated.
25-Nov-2005	18.0	The TO220FM Package has been removed.
14-Dec-2005	19.0	The T <sub>op</sub> on Table 2 has been updated.

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